Patent - ZH oz Attorney's Docket No. 015290-440

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

in re Patent Application of	)
Rajinder Dhindsa et al.	) Group Art Unit: 2813
Application No.: 09/689,845	) Examiner: K. Christianson
Filed: October 13, 2000	) ) hereby certify that this correspondence is being sent
For: STEPPED UPPER ELECTRODE FOR PLASMA PROCESSING UNIFORMITY	by Facsimile Transmission to the Assistant Commissioner For Patents, Washington, D.C. 20231 on:
SIIPPLEMENTAL	Name: BC'ty  AMROPAMENT inted name of person signing the
Assistant Commissioner for Patents	Sign: certificate) Blan
Washington, D.C. 20231	(Signature of person signing the certificate)
Sir:	Date: (Date of Signature)
Further to the Amendment filed December 18, 2001, please amend the application	
as follows.	FAMICOPY RECEIVED

IN THE CLAIMS:

JAN 1 7 2002 TECHNOLOGY CENTER 2800

Please cancel Claims 13 and 20 without prejudice or disclaimer of the subject matter

thereof and replace Claims 12 and 19 as follows:

B

12. (Amended) A method of treating a semiconductor substrate in a plasma chamber, said method comprising the steps of:

supporting the semiconductor substrate on a bottom electrode;

supplying process gas to the chamber;

forming a plasma adjacent an exposed surface of an upper electrode; and

processing the semiconductor substrate with the plasma;